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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/604,651	08/07/2003	Chia-Tien Peng	10958-US-PA	1650	
31561 7:	590 10/03/2005		EXAMINER		
JIANQ CHYUN INTELLECTUAL PROPERTY OFFICE			GHYKA, ALEXANDER G		
7 FLOOR-1, N	IO. 100 ROAD, SECTION 2		ART UNIT	PAPER NUMBER	
TAIPEI, 100	-		2812		
TAIWAN				DATE MAILED: 10/03/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

			
^	Application No.	Applicant(s)	
	10/604,651	PENG ET AL.	
Office Action Summary	Examiner	Art Unit	
	Alexander G. Ghyka	2812	
The MAILING DATE of this communication a	ppears on the cover sheet wit	h the correspondence addr	ess
Period for Reply			
 A SHORTENED STATUTORY PERIOD FOR REP WHICHEVER IS LONGER, FROM THE MAILING Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the main earned patent term adjustment. See 37 CFR 1.704(b). 	DATE OF THIS COMMUNIC 1.136(a). In no event, however, may a rejud will apply and will expire SIX (6) MONT tute, cause the application to become ABA	ATION. ply be timely filed HS from the mailing date of this common (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on	•	•	
·	 nis action is non-final.		
3) Since this application is in condition for allow		rs, prosecution as to the m	nerits is
closed in accordance with the practice under		·	
Disposition of Claims			
4) Claim(s) 1-28 is/are pending in the application	on.	•	
4a) Of the above claim(s) is/are withdr		ALEVANDED OLD #	2.
5) Claim(s) is/are allowed.	·	ALEXANDER GHYK PRIMARY EXAMINE	A
6)⊠ Claim(s) <u>1-28</u> is/are rejected.		B 120 CO	n,
7) Claim(s) is/are objected to.		AN 5812	2/
8) Claim(s) are subject to restriction and	or election requirement.	ale J.	La .
Application Papers			0
9) The specification is objected to by the Examin			
10)⊠ The drawing(s) filed on <u>07 August 2003</u> is/are		•	
Applicant may not request that any objection to the	•	•	
Replacement drawing sheet(s) including the corre			•
11) The oath or declaration is objected to by the	Examiner. Note the attached	Office Action or form PTO	-152.
Priority under 35 U.S.C. § 119			
12)⊠ Acknowledgment is made of a claim for foreig	gn priority under 35 U.S.C. §	119(a)-(d) or (f).	
a)⊠ All b)□ Some * c)□ None of:			
1. Certified copies of the priority docume	nts have been received.		
2. Certified copies of the priority docume	nts have been received in Ap	plication No	
3. Copies of the certified copies of the pri	iority documents have been r	eceived in this National St	age
application from the International Bure		•	
* See the attached detailed Office action for a list	st of the certified copies not re	eceived.	
Attachment(s)			
I) Notice of References Cited (PTO-892)	4) Interview Su	mmary (PTO-413)	
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		/Mail Date ormal Patent Application (PTO-1:	52)
B) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date	6) Other:	, ,	<i>JL</i>

Application/Control Number: 10/604,651

Art Unit: 2812

DETAILED ACTION

Applicants' response of July 21, 2005 has been considered and entered in the record. The Applicants' arguments are not persuasive for the reasons as discussed below.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 12 and 20-28 are rejected under 35 U.S.C. 102(e) as being anticipated by Takayama et al (US 6,610,142) for the reasons as discussed in the previous Office action.

The present claims generally require forming an amorphous silicon layer over a substrate, performing a plasma treatment, transforming the amorphous silicon layer into a polysilicon layer by laser annealing, patterning the polysilicon layer to form a plurality of island polysilicon layers, forming a channel region and a doped source/drain region on each side of the channel region and forming a gate over each channel region.

Takayama et al disclose forming a silicon oxide film, a plasma treatment, the formation of an amorphous silicon film, and its subsequent crystallization by laser

Application/Control Number: 10/604,651

Art Unit: 2812

annealing. See Example 1, column 6, lines 40-65. Takayama et al disclose nitrogen and oxygen containing plasmas (column 5, lines 25-35). Moreover, Takayamea et al discloses the formation of a channel region, source/drain region and gate in the formation of a TFT transistor as required by the present claims. See Example 4, lines 1-60. Even though, Takayama disclose an additional silicon oxide film, the afore mentioned claim limitations are anticipated as the present Claim language does not exclude the additional silicon oxide layer. Takayama discloses that "nucleation sites are controlled by selectively exposing the amorphous silicon film to a plasma". See the Abstract, second to last sentence. Therefore, Claims 1, 12 and 20-29 are anticipated.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-28 area rejected under 35 U.S.C. 103(a) as being unpatentable over Takayama et al (US 6,610,142) in view of Jen et al (JJAP Part 2: Letters 1991, 33 (7B), L997-L979) and Luan et al (Jour. Of Appl. Phys. 1990, 68(7), 3445-3450) for the reasons as discussed in the previous Office action.

Takayama et al is relied upon as discussed above.

Art Unit: 2812

However, Takayama et al do not disclose an ammonià positive shift of the threshold voltage of the TFT or a nitrous oxide hich results in a negative shift threshold voltage.

Jen discloses the formation of a thin film transistor, wherein a nitrous plasma results in a smaller or negative shift of the threshold voltage of 0.5V. See Abstract.

Luan et al disclose the formation of thin film transistors and the effect of NH3 plasma in increasing or positive shift in threshold voltage. See the Abstract and p. 3447, section B.

It would have been obvious to one of ordinary skill in the art, at the time of the invention, that the nitrogen and/or oxygen containing plasma of Takayama et al can be used to adjust the threshold voltage in negative or positive shifts in light of the disclosure of Jen that ammonia plasma results in a positive shift of threshold voltage and the disclosure of Luan et al that nitrous oxide results in a negative shift. A *prima facie* case of obviousness is established, as all of the references pertain to thin film transistors and the use of plasma for the benefit of adjusting the threshold voltage as disclosed in the prior art would be readily apparent to one of ordinary skill in the art.

Response to Applicants' Arguments

Applicants' argue, with respect to both rejections, that Takayama fails to disclose that a plasma treatment is performed to the amorphous silicon layer. Applicants' argue that in Tokayama the plasma treatment is performed to a silicon oxide layer but not to

Page 4

Application/Control Number: 10/604,651

Art Unit: 2812

the amorphous silicon layer. The Examiner maintains that Takayama discloses two plasma treatments, one of which is to the amorphous silicon film. Takayama discloses that "nucleation sites are controlled by selectively exposing the amorphous silicon film to a plasma". See the Abstract, second to last sentence.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Alexander G. Ghyka whose telephone number is (571) 272-1669. The examiner can normally be reached on Monday through Thursday during general business hours.

Art Unit: 2812

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Lebentritt can be reached on (571) 272-1873. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

AGG September 29, 2005 ALEXANDER GHYKA PRIMARY EXAMINER